

Optocoupler, Phototransistor Output, Low Input Current, SSOP-4, Half Pitch, Mini-Flat Package



22628-1



DESCRIPTION

The VOS618A series has a GaAs infrared emitting diode emitter, which is optically coupled to a silicon planar phototransistor detector, and is incorporated in a 4-pin 50 mil lead pitch mini-flat package.

It features a high current transfer ratio at low input current, low coupling capacitance, and high isolation voltage.

The coupling devices are designed for signal transmission between two electrically separated circuits.

FEATURES

- High CTR with low input current
- Low profile package (half pitch)
- High collector emitter voltage, $V_{CEO} = 80\text{ V}$
- Isolation test voltage = 3750 V_{RMS}
- Low coupling capacitance
- High common mode transient immunity
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912



APPLICATIONS

- Telecom
- Industrial controls
- Battery powered equipment
- Office machines
- Programmable controllers

AGENCY APPROVALS

Safety application model number covering all products in this datasheet is VOS618A. This model number should be used when consulting safety agency documents.

- UL1577, file no. E52744
- cUL
- DIN EN 60747-5-5 (VDE 0884-5), available with option 1
- FIMKO EN 60065, EN 60950-1
- CQC GB4943.1-2011 and GB8898-2011 (suitable for installation altitude below 2000 m)

| ORDERING INFORMATION | | | | | | | | | | | | | | | | | | | |
|---|---------------|----------------|----------------|----------------|----------------|---|---|---|---|---|---|---|---|---|---|---|---|---|---|
| <div style="display: flex; justify-content: space-around; align-items: center;"> <div style="text-align: center;"> <table border="1" style="border-collapse: collapse;"> <tr> <td>V</td><td>O</td><td>S</td><td>6</td><td>1</td><td>8</td><td>A</td><td>-</td><td>#</td><td>X</td><td>0</td><td>0</td><td>1</td><td>T</td> </tr> </table> <p>PART NUMBER</p> </div> <div style="text-align: center;"> <p>CTR BIN</p> </div> <div style="text-align: center;"> <p>PACKAGE OPTION</p> </div> <div style="text-align: center;"> <p>TAPE AND REEL</p> </div> <div style="text-align: center;"> <p>SSOP-4 ≥ 5 mm</p> </div> </div> | | | | | | V | O | S | 6 | 1 | 8 | A | - | # | X | 0 | 0 | 1 | T |
| V | O | S | 6 | 1 | 8 | A | - | # | X | 0 | 0 | 1 | T | | | | | | |
| AGENCY CERTIFIED/PACKAGE | CTR (%) | | | | | | | | | | | | | | | | | | |
| | 1 mA | | | | | | | | | | | | | | | | | | |
| UL, cUL, FIMKO, CQC | 50 to 600 | 63 to 125 | 100 to 200 | 80 to 160 | 130 to 260 | | | | | | | | | | | | | | |
| SSOP-4, 50 mil pitch | VOS618AT | VOS618A-2T | VOS618A-3T | VOS618A-7T | VOS618A-8T | | | | | | | | | | | | | | |
| UL, cUL, FIMKO, CQC, VDE (option 1) | 50 to 600 | 63 to 125 | 100 to 200 | 80 to 160 | 130 to 260 | | | | | | | | | | | | | | |
| SSOP-4, 50 mil pitch | VOS618A-X001T | VOS618A-2X001T | VOS618A-3X001T | VOS618A-7X001T | VOS618A-8X001T | | | | | | | | | | | | | | |

Note

- Additional options may be possible, please contact sales office.

| ABSOLUTE MAXIMUM RATINGS ($T_{amb} = 25\text{ }^{\circ}\text{C}$, unless otherwise specified) | | | | |
|--|-----------------------------------|------------|-------------|--------------------|
| PARAMETER | TEST CONDITION | SYMBOL | VALUE | UNIT |
| INPUT | | | | |
| Reverse voltage | | V_R | 6 | V |
| Power dissipation | | P_{diss} | 70 | mW |
| Forward current | | I_F | 50 | mA |
| OUTPUT | | | | |
| Collector emitter voltage | | V_{CEO} | 80 | V |
| Emitter collector voltage | | V_{ECO} | 7 | V |
| Collector current | | I_C | 50 | mA |
| | $t_p/T = 0.5, t_p < 10\text{ ms}$ | I_C | 100 | mA |
| Power dissipation | | P_{diss} | 150 | mW |
| COUPLER | | | | |
| Isolation test voltage between emitter and detector | $t = 1\text{ min}$ | V_{ISO} | 3750 | V_{RMS} |
| Total power dissipation | | P_{tot} | 170 | mW |
| Storage temperature range | | T_{stg} | -55 to +150 | $^{\circ}\text{C}$ |
| Ambient temperature range | | T_{amb} | -55 to +110 | $^{\circ}\text{C}$ |
| Junction temperature | | T_j | 125 | $^{\circ}\text{C}$ |
| Soldering temperature ⁽¹⁾ | $t = 10\text{ s}$ | T_{sld} | 260 | $^{\circ}\text{C}$ |

Notes

- Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute maximum ratings for extended periods of the time can adversely affect reliability.
- ⁽¹⁾ Refer to reflow profile for soldering conditions for surface mounted devices.

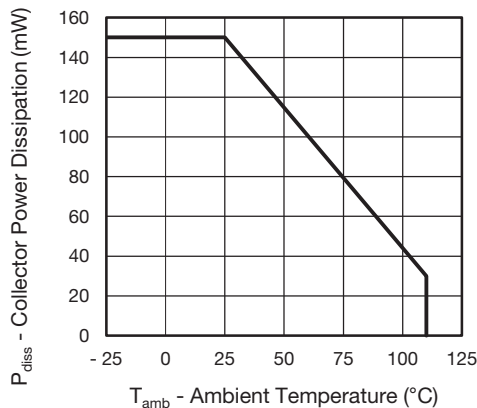


Fig. 1 - Power Dissipation vs. Ambient Temperature



Fig. 2 - Forward Current vs. Ambient Temperature

| ELECTRICAL CHARACTERISTICS ($T_{amb} = 25\text{ }^{\circ}\text{C}$, unless otherwise specified) | | | | | | |
|--|--|-------------|------|------|------|---------------|
| PARAMETER | TEST CONDITION | SYMBOL | MIN. | TYP. | MAX. | UNIT |
| INPUT | | | | | | |
| Forward voltage | $I_F = 50\text{ mA}$ | V_F | | 1.1 | 1.5 | V |
| Reverse current | $V_R = 6\text{ V}$ | I_R | | 0.01 | 10 | μA |
| Input capacitance | $V_F = 0\text{ V}$, $f = 1\text{ MHz}$ | C_I | | 8 | | pF |
| OUTPUT | | | | | | |
| Collector emitter leakage current | $V_{CE} = 10\text{ V}$ | I_{CEO} | | 0.7 | 100 | nA |
| Collector emitter breakdown voltage | $I_C = 100\text{ }\mu\text{A}$ | BV_{CEO} | 80 | | | V |
| Emitter collector breakdown voltage | $I_E = 10\text{ }\mu\text{A}$ | BV_{ECO} | 7 | | | V |
| Collector emitter capacitance | $V_{CE} = 5\text{ V}$, $f = 1\text{ MHz}$ | C_{CE} | | 6 | | pF |
| COUPLER | | | | | | |
| Collector emitter saturation voltage | $I_F = 1\text{ mA}$, $I_C = 0.25\text{ mA}$ | V_{CEsat} | | 0.12 | 0.4 | V |
| Cut-off frequency | $I_F = 10\text{ mA}$, $V_{CC} = 5\text{ V}$, $R_L = 100\text{ }\Omega$ | f_{ctr} | | 119 | | kHz |
| Coupling capacitance | $f = 1\text{ MHz}$ | C_C | | 0.3 | | pF |

Note

- Minimum and maximum values are testing requirements. Typical values are characteristics of the device and are the result of engineering evaluation. Typical values are for information only and are not part of the testing requirements.

| CURRENT TRANSFER RATIO ($T_{amb} = 25\text{ }^{\circ}\text{C}$, unless otherwise specified) | | | | | | | |
|--|---|-----------|--------|------|------|------|------|
| PARAMETER | TEST CONDITION | PART | SYMBOL | MIN. | TYP. | MAX. | UNIT |
| I_C/I_F | $I_F = 1\text{ mA}$, $V_{CE} = 5\text{ V}$ | VOS618A | CTR | 50 | | 600 | % |
| | | VOS618A-2 | CTR | 63 | | 125 | % |
| | | VOS618A-3 | CTR | 100 | | 200 | % |
| | | VOS618A-7 | CTR | 80 | | 160 | % |
| | | VOS618A-8 | CTR | 130 | | 260 | % |

| SWITCHING CHARACTERISTICS ($T_{amb} = 25\text{ }^{\circ}\text{C}$, unless otherwise specified) | | | | | | |
|---|--|-----------|------|------|------|---------------|
| PARAMETER | TEST CONDITION | SYMBOL | MIN. | TYP. | MAX. | UNIT |
| NON-SATURATED | | | | | | |
| Turn on time | $V_{CC} = 5\text{ V}$, $I_C = 2\text{ mA}$, $R_L = 100\text{ }\Omega$ | t_{on} | | 5 | | μs |
| Rise time | | t_r | | 5 | | μs |
| Turn off time | | t_{off} | | 8 | | μs |
| Fall time | | t_f | | 7 | | μs |
| SATURATED | | | | | | |
| Rise and fall time | $I_F = 1.6\text{ mA}$, $V_{CC} = 5\text{ V}$, $R_L = 1.9\text{ k}\Omega$ | t_r | | 10 | | μs |
| Fall time | | t_f | | 11 | | μs |
| Turn on time | | t_{on} | | 14 | | μs |
| Turn off time | | t_{off} | | 12 | | μs |



Fig. 3 - Test Circuit



Fig. 4 - Test Circuit and Waveforms

| SAFETY AND INSULATION RATINGS | | | | |
|---|--|------------|----------------|--------------------|
| PARAMETER | TEST CONDITION | SYMBOL | VALUE | UNIT |
| Climatic classification (according to IEC 68 part 1) | | | 55/110/21 | |
| Comparative tracking index | | CTI | 175 | |
| Maximum rated withstanding isolation voltage | 40 % to 80 % RH, AC test of t = 1 min | V_{ISO} | 3750 | V_{RMS} |
| Maximum transient isolation voltage | | V_{IOTM} | 6000 | V_{peak} |
| Maximum repetitive peak isolation voltage | | V_{IORM} | 565 | V_{peak} |
| Isolation resistance | $T_{amb} = 25\text{ }^{\circ}\text{C}, V_{DC} = 500\text{ V}$ | R_{IO} | $\geq 10^{12}$ | Ω |
| | $T_{amb} = 100\text{ }^{\circ}\text{C}, V_{DC} = 500\text{ V}$ | R_{IO} | $\geq 10^{11}$ | Ω |
| Output safety power | | P_{SO} | 300 | mW |
| Input safety current | | I_{SI} | 200 | mA |
| Input safety temperature | | T_{SI} | 150 | $^{\circ}\text{C}$ |
| Creepage distance | | | ≥ 5 | mm |
| Clearance distance | | | ≥ 5 | mm |
| Insulation thickness | | DTI | ≥ 0.4 | mm |
| Environment (pollution degree in accordance to DIN VDE 0109) | | | 2 | |

Note

- As per IEC 60747-5-5, § 7.4.3.8.2, this optocoupler is suitable for “safe electrical insulation” only within the safety ratings. Compliance with the safety ratings shall be ensured by means of protective circuits.

TYPICAL CHARACTERISTICS ($T_{amb} = 25\text{ }^{\circ}\text{C}$, unless otherwise specified)


Fig. 5 - Forward Voltage vs. Forward Current

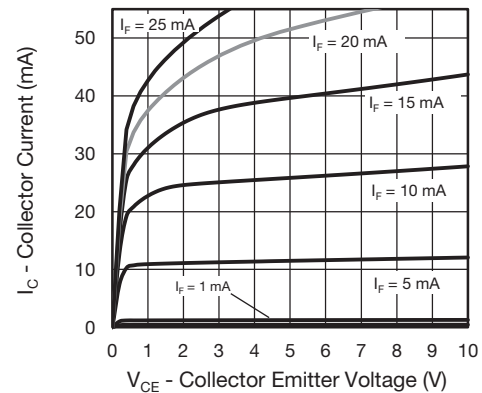


Fig. 6 - Collector Current vs. Collector Emitter Voltage



Fig. 7 - Collector-Emitter Current vs. Ambient Temperature

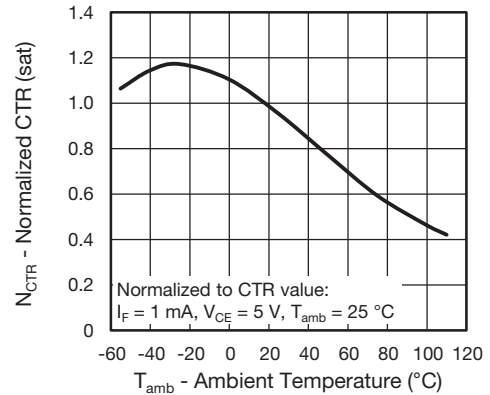


Fig. 10 - Normalized Current Transfer Ratio vs. Ambient Temperature (saturated)



Fig. 8 - Collector Current vs. Collector-Emitter Voltage

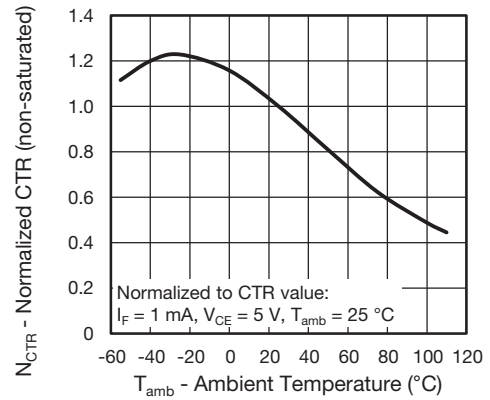


Fig. 11 - Normalized Current Transfer Ratio vs. Ambient Temperature (non-saturated)



Fig. 9 - Collector-Emitter Voltage vs. Ambient Temperature

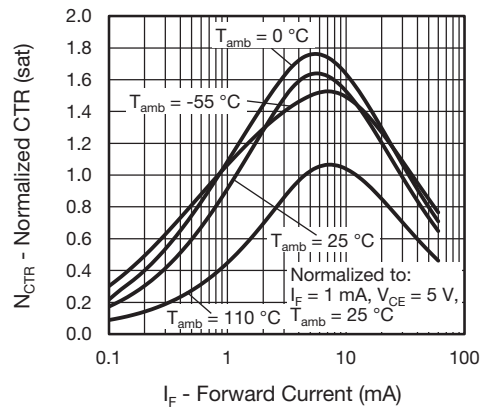


Fig. 12 - Current Transfer Ratio vs. Forward Current (saturated)



Fig. 13 - Current Transfer Ratio vs. Forward Current (non-saturated)



Fig. 16 - Switching Time vs. Load Resistance

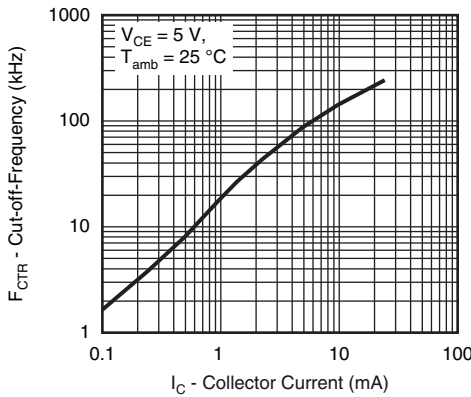


Fig. 14 - Cut-off Frequency (- 3 dB) vs. Collector Current



Fig. 17 - Voltage Gain vs. Frequency

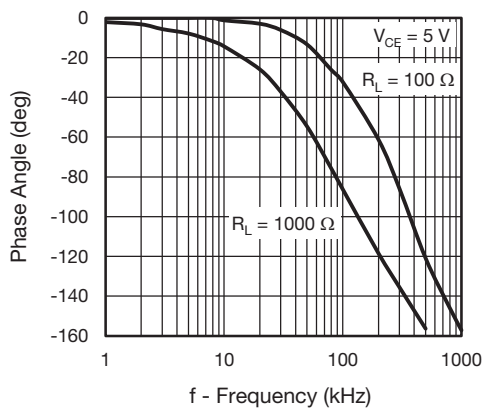


Fig. 15 - Phase Angle vs. Frequency

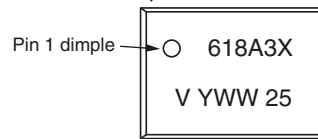


PACKAGE DIMENSIONS in millimeters



22629-2

PACKAGE MARKING (example of VOS618A-3X001T)



Notes

- Option 1 is reflected with letter “X”.
- Tape and reel suffix (T) is not part of the package marking.

TAPE AND REEL DIMENSIONS in millimeters



Fig. 18 - Reel Dimensions (3000 units per reel)

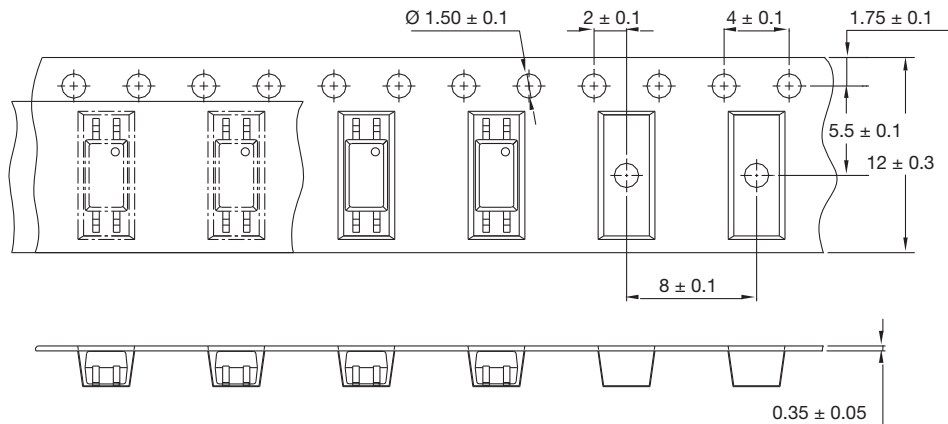


Fig. 19 - Tape Dimensions

SOLDER PROFILE

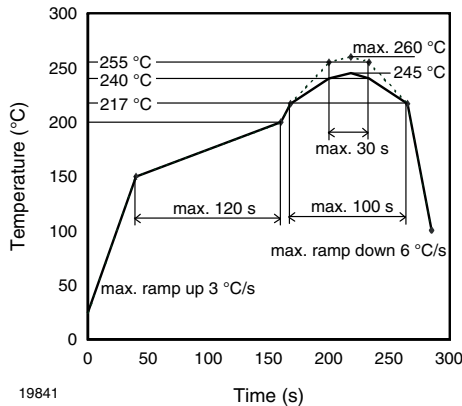


Fig. 20 - Lead (Pb)-free Reflow Solder Profile according to J-STD-020

HANDLING AND STORAGE CONDITIONS

ESD level: HBM class 2

Floor life: unlimited

Conditions: $T_{amb} < 30\text{ °C}$, $RH < 85\%$

Moisture sensitivity level 1, according to J-STD-020



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